## NSN 5961-00-904-0250

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View Online at https://aerobasegroup.com/nsn/5961-00-904-0250 **Inclosure Material:** Glass **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 0.62 amperes forward current, average absolute and 1.60 amperes forward current, average of standard range **Power Rating Per Characteristic:** 0.1 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0